

40819 Transistors

N-Channel; Dual-Gate Tetrode MOSFET

V(BR)DSS (V) 25

V(BR)GSS (V)

I(D) Max. (A) 50m

I(DM) Max. (A) Pulsed I(D)

@Temp (°C)

Absolute Max. Power Diss. (W) 330m

Minimum Operating Temp (°C)

Maximum Operating Temp (°C) 175'

Thermal Resistance Junc-Amb.

V(GS)th Max. (V)

V(GS)th (V) (Min)

@(VDS) (V) (Test Condition)

@I(D) (A) (Test Condition)

I(DSS) Max. (A)

@V(DS) (V) (Test Condition)

@Temp (°C) (Test Condition)

I(GSS) Max. (A) 50n

@V(GS) (V) (Test Condition)

r(DS)on Max. (Ohms)

@V(GS) (V) (Test Condition)

@I(D) (A) (Test Condition)